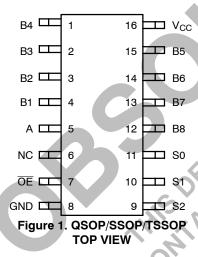
# 8:1 Multiplexer/ Demultiplexer Bus Switch

The ON Semiconductor 74FST3251 is an 8:1, high performance multiplexer/demultiplexer bus switch. The device is CMOS TTL compatible when operating between 4 and 5.5 Volts. The device exhibits extremely low  $R_{\rm ON}$  and adds nearly zero propagation delay. The device adds no noise or ground bounce to the system.

## **Features**

- $R_{ON} < 4 \Omega$  Typical
- Less Than 0.25 ns-Max Delay Through Switch
- Nearly Zero Standby Current
- No Circuit Bounce
- Control Inputs are TTL/CMOS Compatible
- All Popular Packages: QSOP-16, TSSOP-16, SOIC-16
- All Devices in Package TSSOP are Inherently Pb-Free\*



# **TRUTH TABLE**

| _  |     |     |     |                  |
|----|-----|-----|-----|------------------|
|    | Inp | uts | CV  |                  |
| ŌĒ | S2  | S1  | S0  | Function         |
| L  | L   | L ( | Ю.У | A Port = B1 Port |
| L  | L   | L   | Н   | A Port = B2 Port |
| L  | L   | H   | L   | A Port = B3 Port |
| L  | L   | Н   | Н   | A Port = B4 Port |
| L  | Н   | L   | L   | A Port = B5 Port |
| L  | Н   | L   | Н   | A Port = B6 Port |
| L  | Н   | Н   | L   | A Port = B7 Port |
| L  | Н   | Н   | Н   | A Port = B8 Port |
| Н  | Х   | Х   | Χ   | Disconnect       |

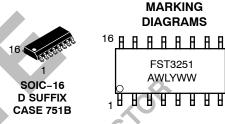
NOTE: H = HIGH Voltage Level, L = LOW Voltage Level, X = Don't Care

1



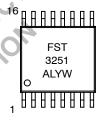
# ON Semiconductor®

http://onsemi.com



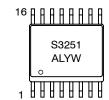


TSSOP-16 DT SUFFIX CASE 948F





QSOP-16 QS SUFFIX CASE 492



A = Assembly Location L, WL = Wafer Lot

Y = Year W, WW = Work Week

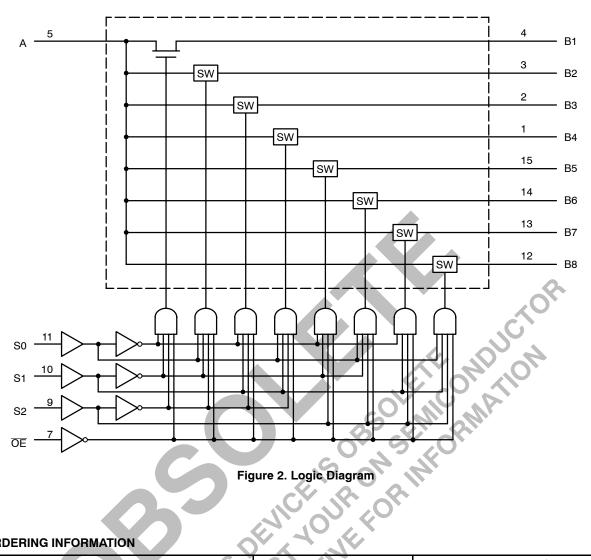
# PIN NAMES

| Pin   | Description        |
|---|--------------------|
| $\overline{OE}_1$ , $\overline{OE}_2$                             | Bus Switch Enables |
| S <sub>0</sub> , S <sub>1</sub>                                   | Select Inputs      |
| Α   | Bus A              |
| B <sub>1</sub> , B <sub>2</sub> , B <sub>3</sub> , B <sub>4</sub> | Bus B              |

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



# **ORDERING INFORMATION**

| Device Order Number | Package                | Shipping <sup>†</sup>    |
|---------------------|------------------------|--------------------------|
| 74FST3251D          | SOIC-16                | 48 Units / Rail          |
| 74FST3251DR2        | SOIC-16                | 1000 Units / Tape & Reel |
| 74FST3251DT         | TSSOP-16*<br>(Pb-Free) | 96 Units / Rail          |
| 74FST3251DTR2       | TSSOP-16*<br>(Pb-Free) | 2500 Units / Tape & Reel |
| 74FST3251QS         | QSOP-16                | 96 Units / Rail          |
| 74FST3251QSR        | QSOP-16                | 2500 Units / Tape & Reel |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>This package is inherently Pb-Free.

#### **MAXIMUM RATINGS**

| Symbol               | Parameter   | Value                  | Unit |
|----------------------|---|------------------------|------|
| V <sub>CC</sub>      | DC Supply Voltage   | -0.5 to +7.0           | V    |
| VI                   | DC Input Voltage  | -0.5 to +7.0           | V    |
| Vo                   | DC Output Voltage   | -0.5 to +7.0           | V    |
| I <sub>IK</sub>      | DC Input Diode Current $V_{I} < GND$  | -50                    | mA   |
| I <sub>OK</sub>      | DC Output Diode Current $V_{O} < GND$   | -50                    | mA   |
| Io                   | DC Output Sink Current  | 128                    | mA   |
| I <sub>CC</sub>      | DC Supply Current per Supply Pin  | ± 100                  | mA   |
| I <sub>GND</sub>     | DC Ground Current per Ground Pin  | ± 100                  | mA   |
| T <sub>STG</sub>     | Storage Temperature Range   | -65 to +150            | °C   |
| TL                   | Lead Temperature, 1 mm from Case for 10 Seconds   | 260                    | °C   |
| $T_J$                | Junction Temperature Under Bias   | + 150                  | °C   |
| $\theta_{\sf JA}$    | Thermal Resistance SOIC TSSOP QSOP  | 125<br>170<br>200      | °C/W |
| MSL                  | Moisture Sensitivity  | Level 1                |      |
| F <sub>R</sub>       | Flammability Rating Oxygen Index: 28 to 34  | UL 94 V-0 @ 0.125 in   |      |
| V <sub>ESD</sub>     | ESD Withstand Voltage  Human Body Model (Note 1)  Machine Model (Note 2)  Charged Device Model (Note 3) | > 2000<br>> 200<br>N/A | ٧    |
| I <sub>Latchup</sub> | Latchup Performance Above V <sub>CC</sub> and Below GND at 85°C (Note 4)                                | ±500                   | mA   |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. Tested to EIA/JESD22-A114-A.
- 2. Tested to EIA/JESD22-A115-A.
- 3. Tested to JESD22-C101-A.
- 4. Tested to EIA/JESD78.

# **RECOMMENDED OPERATING CONDITIONS**

| Symbol          | Parameter   | Min | Max     | Unit |
|-----------------|---|-----|---------|------|
| V <sub>CC</sub> | Supply Voltage Operating, Data Retention Only         | 4.0 | 5.5     | V    |
| VI              | Input Voltage (Note )                                 | 0   | 5.5     | V    |
| Vo              | Output Voltage (HIGH or LOW State)                    | 0   | 5.5     | V    |
| T <sub>A</sub>  | Operating Free-Air Temperature                        | -40 | +85     | °C   |
| Δt/ΔV           | $ \begin{array}{cccccccccccccccccccccccccccccccccccc$ | 0   | DC<br>5 | ns/V |

<sup>5.</sup> Unused control inputs may not be left open. All control inputs must be tied to a high or low logic input voltage level.

# DC ELECTRICAL CHARACTERISTICS

|                 |                                       |  | V <sub>cc</sub> | T <sub>A</sub> = - | 40°C to | +85°C |      |
|-----------------|---------------------------------------|--|-----------------|--------------------|---------|-------|------|
| Symbol          | Parameter                             | Conditions   | (V)             | Min                | Тур*    | Max   | Unit |
| V <sub>IK</sub> | Clamp Diode Resistance                | $I_{IN} = -18mA$   | 4.5             |                    |         | -1.2  | V    |
| V <sub>IH</sub> | High-Level Input Voltage              |  | 4.0 to 5.5      | 2.0                |         |       | V    |
| V <sub>IL</sub> | Low-Level Input Voltage               |  | 4.0 to 5.5      |                    |         | 0.8   | V    |
| lį              | Input Leakage Current                 | $0\leqV_{IN}\leq5.5\;V$  | 5.5             |                    |         | ±1.0  | μΑ   |
| l <sub>OZ</sub> | OFF-STATE Leakage Current             | $0 \le A, B \le V_{CC}$  | 5.5             |                    |         | ±1.0  | μΑ   |
| R <sub>ON</sub> | Switch On Resistance (Note 6)         | $V_{IN} = 0 \text{ V}, I_{IN} = 64 \text{ mA}$                 | 4.5             |                    | 4       | 7     | Ω    |
|                 |                                       | $V_{IN} = 0 \text{ V}, I_{IN} = 30 \text{ mA}$                 | 4.5             |                    | 4       | 7     |      |
|                 |                                       | V <sub>IN</sub> = 2.4 V, I <sub>IN</sub> = 15 mA               | 4.5             |                    | 8       | 15    |      |
|                 |                                       | V <sub>IN</sub> = 2.4 V, I <sub>IN</sub> = 15 mA               | 4.0             |                    | 11      | 20    |      |
| I <sub>CC</sub> | Quiescent Supply Current              | V <sub>IN</sub> = V <sub>CC</sub> or GND, I <sub>OUT</sub> = 0 | 5.5             |                    |         | 3     | μΑ   |
| $\Delta I_{CC}$ | Increase In I <sub>CC</sub> per Input | One input at 3.4 V, Other inputs at $V_{CC}$ or GND            | 5.5             |                    |         | 2.5   | mA   |

# **AC ELECTRICAL CHARACTERISTICS**

|                                     |  |                                  |                     | $T_A = -40$ °C to $+85$ °C<br>$C_L = 50$ pF, RU = RD = 500 $\Omega$ |                   |       |      |
|-------------------------------------|--|----------------------------------|---------------------|---|-------------------|-------|------|
|                                     |  | 05                               | V <sub>CC</sub> = 4 | .5-5.5 V  | V <sub>CC</sub> = | 4.0 V |      |
| Symbol                              | Parameter  | Conditions                       | Min                 | Max   | Min               | Max   | Unit |
| t <sub>PHL</sub> , t <sub>PLH</sub> | Prop Delay Bus to Bus (Note 7)                   | V <sub>I</sub> = OPEN            |                     | 0.25  |                   | 0.25  | ns   |
|                                     | Prop Delay, Select to Bus A                      | 4, 0                             | 1.0                 | 6.3   |                   | 6.9   | 1    |
| t <sub>PZH</sub> , t <sub>PZL</sub> | Output Enable Time, Select to Bus B              | $V_I = 7 \text{ V for } t_{PZL}$ | 1.0                 | 6.0   |                   | 6.5   | ns   |
|                                     | Output Enable Time, I <sub>OE</sub> to Bus A, B  | $V_I = OPEN$ for $t_{PZH}$       | 1.0                 | 6.0   |                   | 6.5   |      |
| t <sub>PHZ</sub> , t <sub>PLZ</sub> | Output Disable Time, Select to Bus B             | $V_I = 7 V \text{ for } t_{PLZ}$ | 1.0                 | 5.8   |                   | 6.5   | ns   |
|                                     | Output Disable Time, I <sub>OE</sub> to Bus A, B | $V_I = OPEN$ for $t_{PHZ}$       | 1.0                 | 5.8   |                   | 6.5   |      |

<sup>7.</sup> This parameter is guaranteed by design but is not tested. The bus switch contributes no propagation delay other than the RC delay of the typical On resistance of the switch and the 50 pF load capacitance, when driven by an ideal voltage source (zero output impedance).

# **CAPACITANCE** (Note 8)

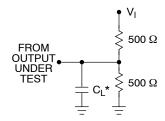
| Symbol           | Parameter                       | Conditions                              | Тур | Max | Unit |
|------------------|---------------------------------|---|-----|-----|------|
| C <sub>IN</sub>  | Control Pin Input Capacitance   | V <sub>CC</sub> = 5.0 V                 | 3   |     | pF   |
| C <sub>I/O</sub> | A Port Input/Output Capacitance | V <sub>CC</sub> , <del>OE</del> = 5.0 V | 13  |     | pF   |
| C <sub>I/O</sub> | B Port Input/Output Capacitance | V <sub>CC</sub> , <del>OE</del> = 5.0 V | 5   |     | pF   |

<sup>8.</sup>  $T_A = +25$ °C, f = 1 MHz, Capacitance is characterized but not tested.

<sup>\*</sup>Typical values are at V<sub>CC</sub> = 5.0 V and T<sub>A</sub> = 25°C.

6. Measured by the voltage drop between A and B pins at the indicated current through the switch. On resistance is determined by the lower of the voltages on the two (A or B) pins.

# **AC Loading and Waveforms**



#### NOTES:

- 1. Input driven by 50  $\Omega$  source terminated in 50  $\Omega$ .
- 2. CL includes load and stray capacitance.
- $*C_L = 50 pF$

Figure 3. AC Test Circuit

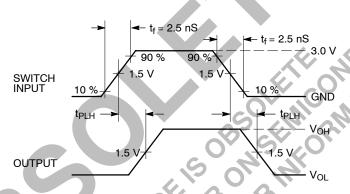


Figure 4. Propagation Delays

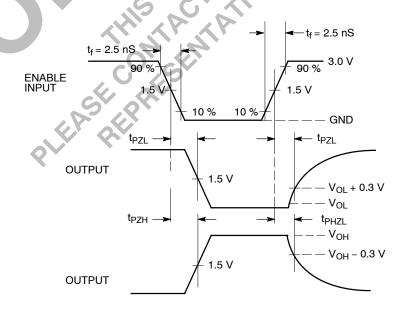
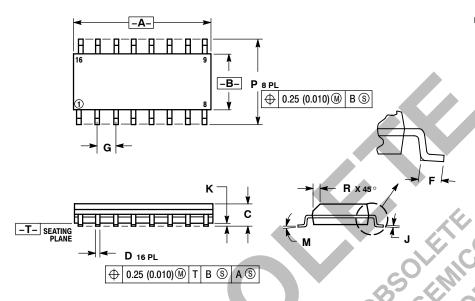


Figure 5. Enable/Disable Delays

#### PACKAGE DIMENSIONS

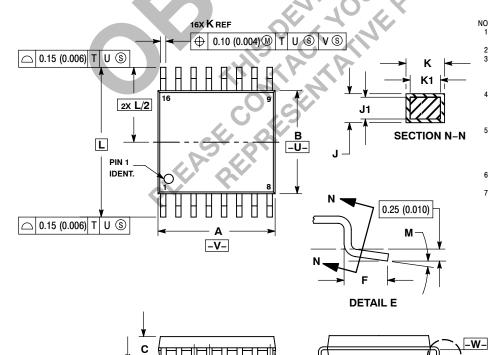
# SOIC-16 **DW SUFFIX** CASE 751B-05 **ISSUE J**



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

|     | MILLIN | IETERS | INC   | HES   |  |
|-----|--------|--------|-------|-------|--|
| DIM | MIN    | MAX    | MIN   | MAX   |  |
| Α   | 9.80   | 10.00  | 0.386 | 0.393 |  |
| В   | 3.80   | 4.00   | 0.150 | 0.157 |  |
| С   | 1.35   | 1.75   | 0.054 | 0.068 |  |
| D   | 0.35   | 0.49   | 0.014 | 0.019 |  |
| F   | 0.40   | 1.25   | 0.016 | 0.049 |  |
| G   | 1.27   | BSC    | 0.050 | BSC   |  |
| J   | 0.19   | 0.25   | 0.008 | 0.009 |  |
| K   | 0.10   | 0.25   | 0.004 | 0.009 |  |
| M   | 0°     | 7°     | 0°    | 7°    |  |
| P   | 5.80   | 6.20   | 0.229 | 0.244 |  |
| R   | 0.25   | 0.50   | 0.010 | 0.019 |  |





G

0.10 (0.004)

-T- SEATING PLANE

#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- T 14.3M, 1902.

  CONTROLLING DIMENSION: MILLIMETER.

  DIMENSION A DOES NOT INCLUDE MOLD FLASH.

  PROTRUSIONS OR GATE BURRS. MOLD FLASH

  OR GATE BURRS SHALL NOT EXCEED 0.15
- ON GATE BURHS SHALL NOT EXCEED 0.15
  (0.006) PER SIDE.

  DIMENSION B DOES NOT INCLUDE INTERLEAD
  FLASH OR PROTRUSION. INTERLEAD FLASH OR
  PROTRUSION SHALL NOT EXCEED
  0.25 (0.010) PER SIDE.
- 0.25 (0.010) FER SIDE.

  DIMENSION K DOES NOT INCLUDE DAMBAR
  PROTRUSION. ALLOWABLE DAMBAR
  PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN
  EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
  6. TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY.

  7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

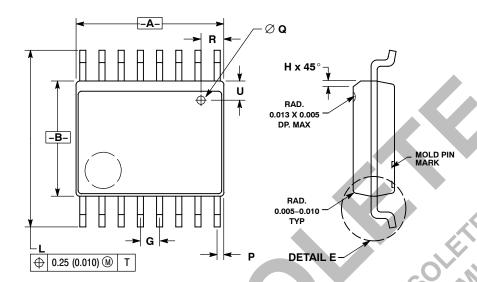
|     | MILLIN | IETERS | INC       | HES   |  |
|-----|--------|--------|-----------|-------|--|
| DIM | MIN    | MAX    | MIN       | MAX   |  |
| Α   | 4.90   | 5.10   | 0.193     | 0.200 |  |
| В   | 4.30   | 4.50   | 0.169     | 0.177 |  |
| С   |        | 1.20   |           | 0.047 |  |
| D   | 0.05   | 0.15   | 0.002     | 0.006 |  |
| F   | 0.50   | 0.75   | 0.020     | 0.030 |  |
| G   | 0.65   | BSC    | 0.026     | BSC   |  |
| Н   | 0.18   | 0.28   | 0.007     | 0.011 |  |
| J   | 0.09   | 0.20   | 0.004     | 0.008 |  |
| J1  | 0.09   | 0.16   | 0.004     | 0.006 |  |
| K   | 0.19   | 0.30   | 0.007     | 0.012 |  |
| K1  | 0.19   | 0.25   | 0.007     | 0.010 |  |
| L   | 6.40   |        | 0.252 BSC |       |  |
| M   | 0°     | 8°     | 0°        | 8°    |  |

**DETAIL E** 

#### PACKAGE DIMENSIONS

# QSOP-16 **QS SUFFIX**

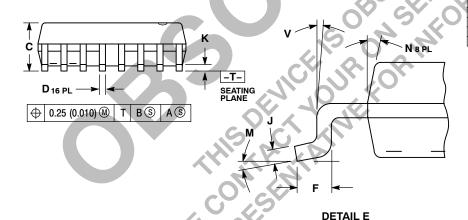
CASE 492-01 **ISSUE O** 



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
  THE BOTTOM PACKAGE SHALL BE BIGGER THAN THE TOP PACKAGE BY 4 MILS (NOTE: LEAD SIDE ONLY). BOTTOM PACKAGE DIMENSION SHALL FOLLOW THE DIMENSION STATED IN THIS DRAWING.
- PLASTIC DIMENSIONS DOES NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 6 MILS PER
- BOTTOM EJECTOR PIN WILL INCLUDE THE COUNTRY OF ORIGIN (COO) AND MOLD CAVITY I.D.

|     | INC    | HES    | MILLIMETERS |       |
|-----|--------|--------|-------------|-------|
| DIM | MIN    | MAX    | MIN         | MAX   |
| Α   | 0.189  | 0.196  | 4.80        | 4.98  |
| В   | 0.150  | 0.157  | 3.81        | 3.99  |
| С   | 0.061  | 0.068  | 1.55        | 1.73  |
| D   | 0.008  | 0.012  | 0.20        | 0.31  |
| F   | 0.016  | 0.035  | 0.41        | 0.89  |
| G   | 0.025  | BSC    | 0.64        | BSC   |
| H   | 0.008  | 0.018  | 0.20        | 0.46  |
| J   | 0.0098 | 0.0075 | 0.249       | 0.191 |
| K   | 0.004  | 0.010  | 0.10        | 0.25  |
| L   | 0.230  | 0.244  | 5.84        | 6.20  |
| M   | 0°     | 8°     | 0°          | 8°    |
| N   | 0 °    | 7°     | 0°          | 7°    |
| P   | 0.007  | 0.011  | 0.18        | 0.28  |
| Q   | 0.020  | DIA    | 0.51 DIA    |       |
| R   | 0.025  | 0.035  | 0.64        | 0.89  |
| U   | 0.025  | 0.035  | 0.64        | 0.89  |
| ٧   | 0°     | 8°     | 0°          | 8 °   |



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